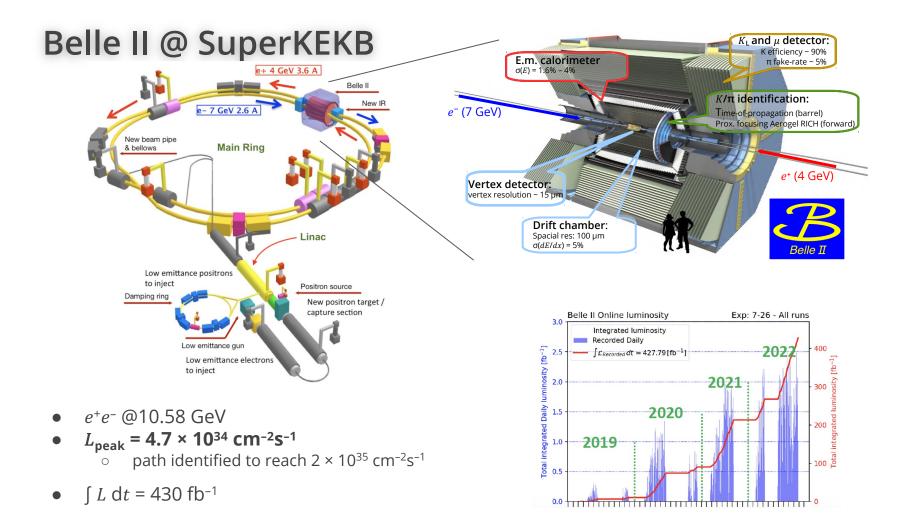
## SiPM studies for the upgrade of the e.m. calorimeter of the Belle II detector

<u>Claudia Cecchi</u>, Elisa Manoni, Stefano Moneta (PERUGIA) Marcello Campajola, Guglielmo De Nardo, , Mario Merola (NAPOLI)







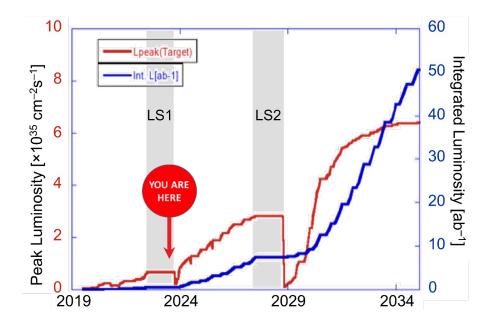
## Belle II future upgrade

First long-shutdown (LS1) just concluded

Belle II will undergo a significant upgrade during 2027 long-shutdown (**LS2**):

- Vertexing, tracking and PID
- MDI re-design
  - Reduce machine backgrounds to cope with 6x10<sup>35</sup> cm<sup>-2</sup>s<sup>-1</sup> luminosity

- Improve electron and neutral particle reconstruction: electromagnetic calorimeter (ECL)
  - possible **bottleneck** at high luminosity
  - longer term timescale (> 2030)

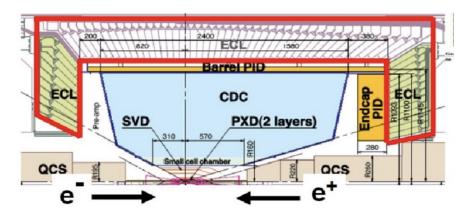


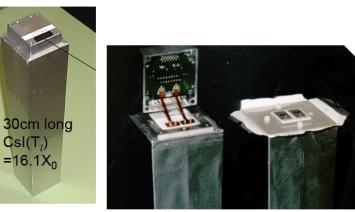
## ECL @Belle II

#### Same from Belle

- 8736 **Csl(Tl) crystals** 30x5x5 cm<sup>3</sup> (~16 X<sub>0</sub>)
- Pin diodes (2 x crystal)
- Charge sensitive preamplifier (CSP)
- **Shaper** (500 ns)
- **Digitizer** (1.7 MHz)
- FPGA to fit waveform







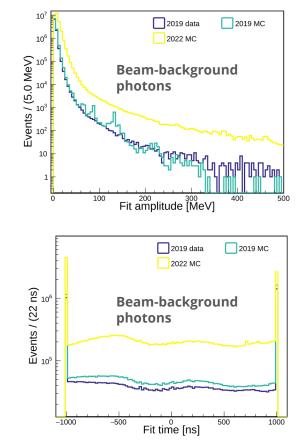
## ECL upgrade scenarios

Higher rate and occupancy with increasing luminosity

- Low energy spectrum dominated by beam-background
- Performance degradation in the low energy region: impact soft photons and π<sup>0</sup> reconstruction

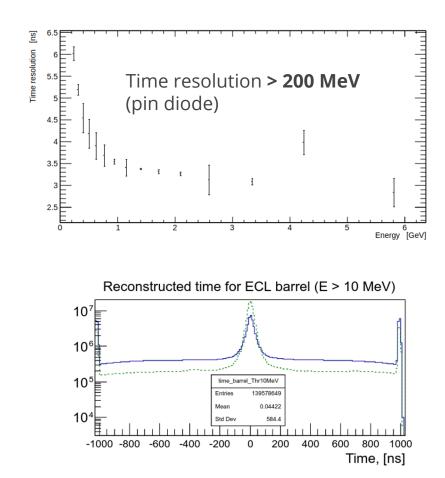
Possible solutions:

- a) New crystals with shorter decay time (pure Csl, PWO, BSO...)
  - i) reject out of time beam background
  - ii) APD readout studied in a past R&D <u>JINST 12 C07032</u>
  - iii) high impact and very expensive solution
- b) New photodetector, use same CsI(Tl) crystals
  - i) fast timing for rejecting beam-background  $\rightarrow$  need **internal gain**
  - ii) exploit the very high LY of CsI(Tl) for the energy reconstruction
  - iii) investigated APD, new R&D with **SiPM**



## SiPM readout option

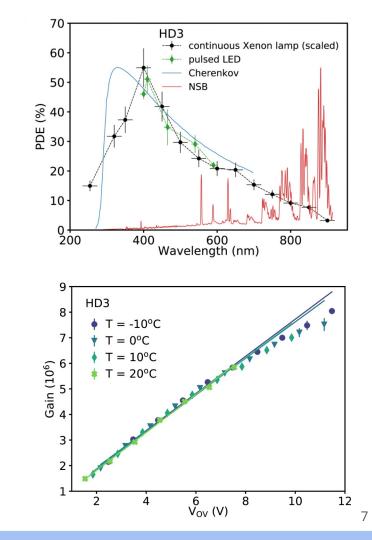
- Simpler and cheaper wrt APD
- Good solution for **timing**, even at **low energy** 
  - reject beam background photons
- Not the optimal option for **amplitude measurement** (loss of linearity at high p.e. yield)
  - expected improvement with future developments
  - keep existing pin diodes for energy measurement, use SiPM for timing in the low energy region
- Beyond CsI(Tl), different crystals investigated:
  - pure Csl, LYSO, LaBr<sub>3</sub>, BGO
- Possible synergy with FCC dual-readout homogeneous calorimeter R&D



## Test with SiPM prototype

Originally designed by **FBK** for CTA, characterized in <u>NIM A</u> <u>1049, 168023 (2023)</u>

- NUV-enhanced (P.D.E. about 35% @350 nm)
  - **optimized for pure Csl** or **LaBr**<sub>3</sub> emission
  - also to detect **Cherenkov light** emission in CsI(Tl)
- Area 6x6 mm<sup>2</sup> (effective active area ~80%, 40 μm pitch)
- Breakdown  $V_B \sim 26.5 V$
- At O.V. +4.5 V  $\rightarrow$  Gain = 3.5 x 10<sup>6</sup> electrons/p.e.



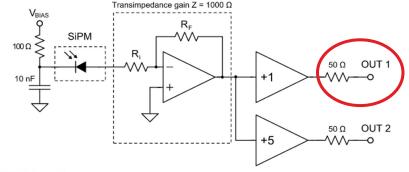
### SiPM readout

AdvanSid Board Signal amplifier

- <u>Transimpedance amplifier</u>: **gain**  $G_{out} = 500 \Omega$
- Takes directly the SiPM bias
- Power supply: ±5 V

Output signal amplitude is proportional to collected photo-electrons





## **Experimental setup**

#### • Test different crystals

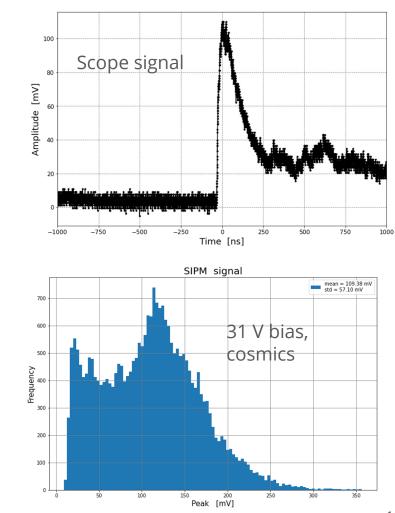
- Pure Csl from Amcrys
- CsI (TI) from old Belle ECL
- LYSO from SuperB
- $\circ$  LaBr<sub>3</sub> from Saint Gobain
- Couple SiPM directly to crystal surface with Silicone <u>optical grease</u> (<u>EJ-550</u>)
- All crystals are wrapped with teflon + mylar foils
- Trigger cosmics with scintillator (coupled to PMT) or use radioactive source spectrum
- Save full waveforms at the scope reading the AdvanSid



## Pure Csl + SiPM

- 30x6x6 cm<sup>3</sup>
- Low LY but short decay time (~ 10 ns)
- SiPM discharge time dominates in the waveform
- Energy spectrum with cosmics

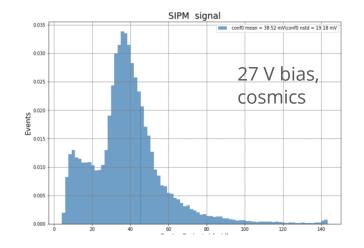
	CsI (TI)	Csl pure	
Density (g/cm <sup>3</sup> )	4.51	4.51	
λ max emission (nm)	550	310	
Light yield ( $\gamma$ /keV)	54	2	
Primary decay time (ns)	1000	10	
Hygroscopic	yes		

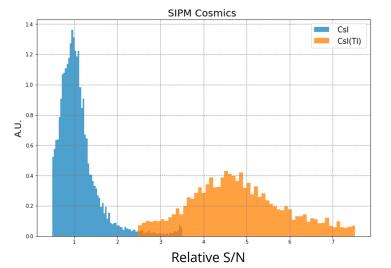


## CsI(TI) + SiPM

- 30x6x6 cm<sup>3</sup>
- High LY but very long decay time (~ 1 µs)
- Good energy resolution with cosmics
  - Compare pure CsI and CsI(Tl)

	CsI (TI)	CsI pure	
Density (g/cm <sup>3</sup> )	4.51	4.51	
λ max emission (nm)	550	310	
Light yield ( $\gamma$ /keV)	54	2	
Primary decay time (ns)	1000	10	
Hygroscopic	yes		

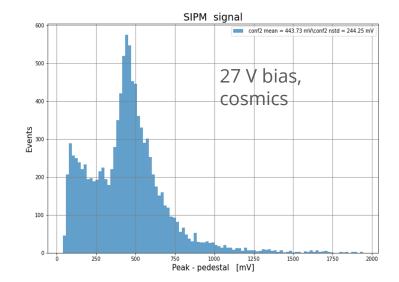




## LYSO + SiPM

- 20x3x3 cm<sup>3</sup>, slightly trapezoidal shape
- High light-yield and fast decay time (36 ns)
  - $\circ$  useful as a cross-check (LY ~ Csl(Tl) )
- Sharp peak observed in amplitude spectrum
  - with faster emission, also energy resolution improves

Table comparing principal properties	LYSO
Density [g/cm <sup>3</sup> ]	7.1
Attenuation length for 511 keV (cm)	1.2
Decay time [ns]	36
Energy resolution @ 662 keV	8.0
Light output, photons per keV	33

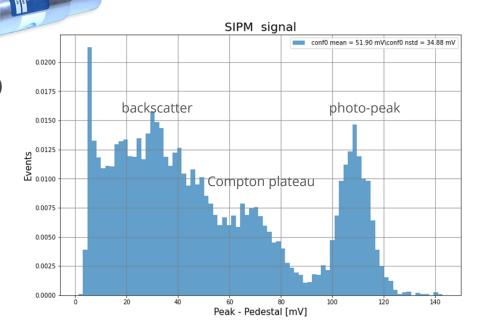


## LaBr<sub>3</sub> + SiPM

One crystal from Saint-Gobain:

- Cylinder 25 mm diameter x 25 mm height
- High light-yield and short decay time (16 ns)
- Very good energy resolution with <sup>137</sup>Cs source

Properties	Standard LaBr <sub>3</sub> (Ce)	Enhanced LaBr <sub>3</sub> (Ce+Sr)	
Energy Resolution @ 662KeV	2.6%	2.2%	
<b>Photoelectron yield</b> [% of Nal(Tl)] (for γ-rays)	165	>190	
Wavelength of emission max [nm]	380	385	
Primary decay time [µs]	0.016	0.025	
Light yield [photons/keVγ]	63	73	
Refractive index @ emission max.	~1.9	~2.0	
Density [g/cm³]	5.08		
Hygroscopic	yes		

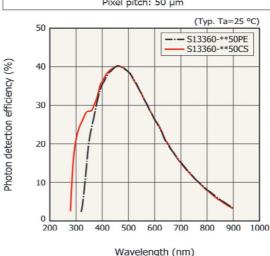


## Planned tests with Hamamatsu SiPM

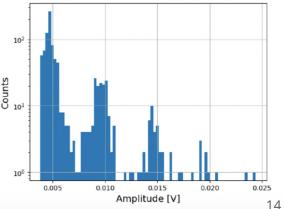
**S13360-6050CS** SiPM are going to be tested

- Non UV-enhanced  $\rightarrow$  optimized for CsI(TI) emission
- 50 µm pitch already tested @Napoli, 25 µm pitch on the pipe

Type no.	Pixel pitch (µm)	Effective photosensitive area (mm)	Number of pixels	Package	Fill factor (%)	
S13360-1325PE		$1.3 \times 1.3$	2668	Glass epoxy		
S13360-3025CS		3.0 × 3.0	14400	Ceramic		
S13360-3025PE	25	3.0 × 3.0	14400	Glass epoxy	47	
S13360-6025CS			E7600	Ceramic		
S13360-6025PE		$6.0 \times 6.0$	57600	Glass epoxy		
S13360-1350PE		1.3 × 1.3	667	Glass epoxy		
S13360-3050CS		3.0 × 3.0	3600	Ceramic		
S13360-3050PE	50	5.0 × 5.0		Glass epoxy	74	
S13360-6050CS		$6.0 \times 6.0$	14400	Ceramic		
S13360-6050PE		0.0 × 0.0	14400	Glass epoxy		
S13360-1375PE		1.3 × 1.3	285	Glass epoxy		
S13360-3075CS	75	CS 3.0 × 3.0		1600	Ceramic	
S13360-3075PE		3.0 × 3.0	Glass epoxy		82	
S13360-6075CS		6.0 × 6.0	6400	Ceramic		
S13360-6075PE		0.0 × 0.0	6400	Glass epoxy		



#### SIPM dark counts spectrum

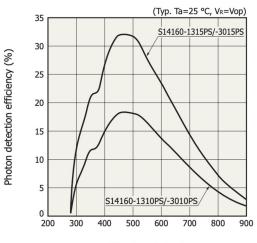


Pixel pitch: 50 µm

## Planned tests with Hamamatsu SiPM

#### S14160 SiPM o be tested

Typ. no.	Number of channels (ch)	Effective photosensitive area/channel (mm <sup>2</sup> )	Pixel pitch (µm)	Number of pixels/channel	Package	Window	Window refractive index	Geometrical fill factor (%)
S14160-3050HS		3.0 × 3.0		3531				
S14160-4050HS	] 1	4.0 × 4.0		6331				
S14160-6050HS		6.0 × 6.0		14331	Curford			
S14161-3050HS-04	16 (4 × 4)	3.0 × 3.0	50	3531	Surface mount type	Silicone	1.57	74
S14161-3050HS-08	64 (8 × 8)	3.0 × 3.0		3531	mount type			
S14161-4050HS-06	36 (6 × 6)	$4.0 \times 4.0$		6331				
S14161-6050HS-04	16 (4 × 4)	6.0 × 6.0		14331				

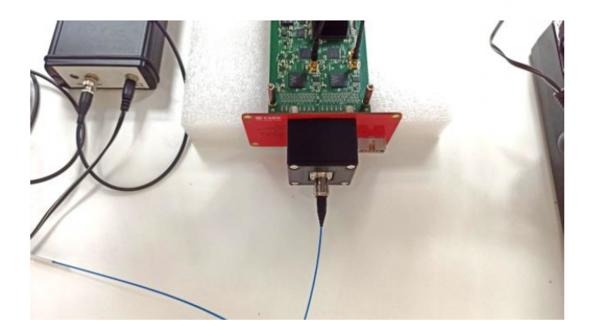


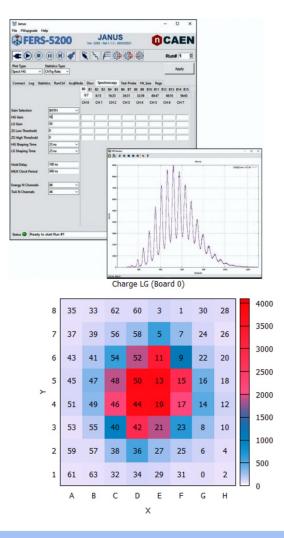
Wavelength (nm)

Darameter	Symbol	S14160				
Parameter		-1310PS	-3010PS	-1315PS	-3015PS	Unit
Effective photosensitive area	-	$1.3 \times 1.3$	3 × 3	$1.3 \times 1.3$	3 × 3	mm
Pixel pitch	-	10		15		μm
Number of pixels	-	16663	89984	7284	39984	-
Geometrical fill factor	-	31		49		%
Package	-	Surface mount type			-	
Window	-	Silicone resin			-	
Window refractive index	-	1.57			-	

## **Read-out options**

Test complementary options in Perugia and Napoli





## Readout option (@Napoli)

# A COST AND A COST AND

#### • <u>CITIROC-1A</u>

- 64 ch frontend
- Onboard power supply with temperature correction

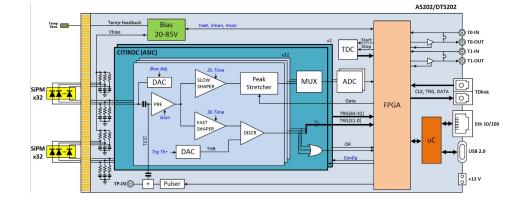
#### Readout scheme:

- Each channel:
  - preamplifier
  - slow shaper with peak sensing (variable shaping time)
  - fast shaper followed by a discriminator
- Output:
  - integrated charge

Analogous strategy @PG:

- Cremat chip with CSP + fast shaper (50 ns)
- To be integrated in custom-made board





## Readout option (@Perugia)

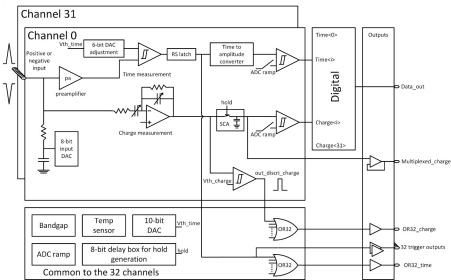


#### CAEN DT5550W with PETIROC-2A

- On-board Power Supply for SiPM Bias
- Measure both first incident photon timing and whole crystal light charge integration
- 10-bit ADC + 40 ps TDC

## Ideal solution for highly accurate **SiPM timing applications**





## Summary

The Belle II community will soon need to define a scenario for an upgrade of the e.m. calorimeter

- Fundamental detector for *B* **physics**
- The increase in luminosity @Belle II could lead to a significative performance degradation
- Full redesign of the calorimeter may not be feasible  $\rightarrow$  investigate **low-impact solutions**
- A **SiPM readout** represents an interesting option
  - fully exploit the **high light-yield** of **CsI(Tl)** crystals
  - $\circ$  recover good **time resolution** at **low energy** deposits  $\rightarrow$  reject overlapping **beam-backgrounds**
  - need to deal with **limited dynamic range**
- We are looking forward further development in the field (test of various crystals to be used in different future project like FCC)

# Backup

## Performance of PIN diode, APD, SiPM

	<b>PIN</b> [55]	<b>APD</b> [56]	<b>SiPM</b> [50]
	(SFH2704)	(S12053-05)	(C10010)
Gain	1	1 - 50	$2 \times 10^{5}$
Output Type	Analogue	Analogue	Analogue or Digital
Operational Bias (V)	6	150 - 200	24.2 - 24.7
Overvoltage (V)	-	-	1 - 5
Spectral Range (nm)	400 to 1100	200 to 1000	300 to 950
Peak Sensitivity (nm)	900	620	420*
PDE/QE (%)	-	80	18 **
Capacitance (pF)	13.4	5	50
Max Photocurrent (µA)	1.22	84	$16 \times 10^{3}$
Dark Current (nA)	0.1 - 25	0.2 - 5	1 - 10
Area (mm <sup>2</sup> )	3.6	21.24	2.4
Active Area (mm <sup>2</sup> )	1.51	7.07	1
Responsivity (A/W)	0.34	21	$4 \times 10^{3}$
Rise Time (ns)	47	0.875	0.3